

# Critical current in thin flat superconductors with Bean-Livingston and geometrical barriers

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Dependence of the critical current  $I_c$  on the applied magnetic field  $H_a$  is theoretically studied for a thin superconducting strip of a rectangular cross section, taking an interplay between the Bean-Livingston and the geometric barriers in the sample into account. It is assumed that bulk vortex pinning is negligible, and the London penetration depth  $\lambda$  is essentially less than the thickness  $d$  of the strip. As is known, the Bean-Livingston barrier results from the attraction of vortices to the sample surface at distances of the order of  $\lambda$ , while the geometrical barrier is due to the shape of superconductors, and it develops on the scale of the order of  $d$ . In the familiar approach to the calculation of  $I_c(H_a)$  [1], the sample is considered as an infinitely thin strip, and the barriers are modelled by the condition that the Lorentz force at the distance  $\sim d$  from the edge of the strip should reach a certain critical value for vortices to penetrate into the sample. However, to investigate the effect of these barriers on  $I_c$  more rigorously, one cannot neglect the thickness of the strip. In the present work a two-dimensional distribution of the current over the cross section of the sample is found under the assumption that a vortex dome exists in the strip. In obtaining this result the approach of [2] is exploited which is based on the methods of conformal mappings. With this distribution the dependence  $I_c(H_a)$  is calculated. This dependence is determined by the ratio  $p \equiv (\lambda/d)^{1/3} \kappa / \ln(\kappa)$ , where  $\kappa$  is the Ginsburg-Landau parameter. If  $p$  exceeds a critical value, the critical current is mainly determined by the Bean-Livingston barrier, otherwise the geometrical barrier prevails at low  $H_a$ . In the latter case a crossover between the two types of the dependences  $I_c(H_a)$  occurs with increasing magnetic field.

## References

- [1] M. Benkraouda, J.M. Clem, Phys. Rev. B **58**, 15103 (1998).
- [2] E.H. Brandt, G.P. Mikitik, E. Zeldov, JETP **117**, 439 (2013).

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